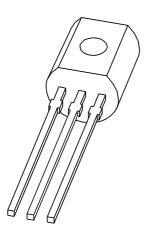
DISCRETE SEMICONDUCTORS

DATA SHEET



2N5401PNP high-voltage transistor

Product specification
Supersedes data of 1997 May 22

1999 Apr 08





PNP high-voltage transistor

2N5401

FEATURES

• Low current (max. 300 mA)

• High voltage (max. 150 V).

APPLICATIONS

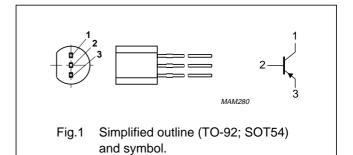
- General purpose switching and amplification
- Telephony applications.

DESCRIPTION

PNP high-voltage transistor in a TO-92; SOT54 plastic package. NPN complement: 2N5551.

PINNING

| PIN | DESCRIPTION |
|-----|-------------|
| 1 | collector |
| 2 | base |
| 3 | emitter |



LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | UNIT |
|------------------|-------------------------------|--------------------------|------|------------|------|
| V _{CBO} | collector-base voltage | open emitter | _ | -160 | V |
| V _{CEO} | collector-emitter voltage | open base | _ | -150 | ٧ |
| V _{EBO} | emitter-base voltage | open collector | _ | - 5 | V |
| I _C | collector current (DC) | | _ | -300 | mA |
| I _{CM} | peak collector current | | _ | -600 | mA |
| I _{BM} | peak base current | | _ | -100 | mA |
| P _{tot} | total power dissipation | T _{amb} ≤ 25 °C | _ | 630 | mW |
| T _{stg} | storage temperature | | -65 | +150 | °C |
| Tj | junction temperature | | _ | 150 | °C |
| T _{amb} | operating ambient temperature | | -65 | +150 | °C |

Philips Semiconductors Product specification

PNP high-voltage transistor

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THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | CONDITIONS | VALUE | UNIT |
|---------------------|---|------------|-------|------|
| R _{th j-a} | thermal resistance from junction to ambient | note 1 | 200 | K/W |

Note

1. Transistor mounted on an FR4 printed-circuit board.

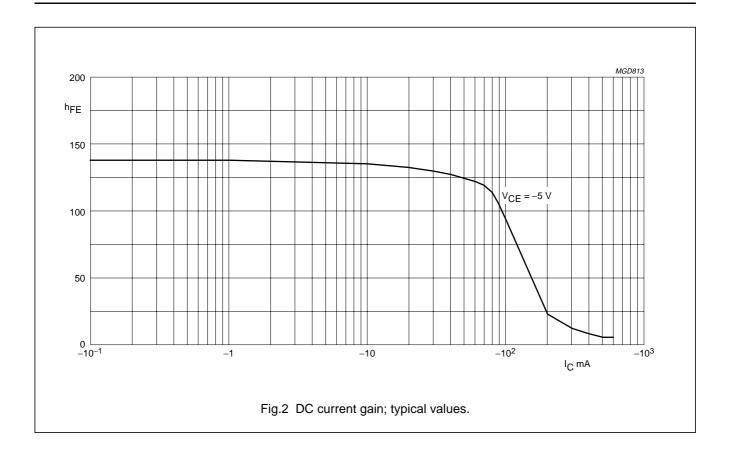
CHARACTERISTICS

 T_{amb} = 25 °C unless otherwise specified.

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | UNIT |
|--------------------|--------------------------------------|---|------|------|------|
| I _{CBO} | collector cut-off current | I _E = 0; V _{CB} = -120 V | _ | -50 | nA |
| | | I _E = 0; V _{CB} = -120 V; T _{amb} = 100 °C | _ | -50 | μΑ |
| I _{EBO} | emitter cut-off current | I _C = 0; V _{EB} = -4 V | _ | -50 | nA |
| h _{FE} | DC current gain | $I_C = -1$ mA; $V_{CE} = -5$ V; see Fig.2 | 50 | _ | |
| | | $I_C = -10 \text{ mA}; V_{CE} = -5 \text{ V}; \text{ see Fig.2}$ | 60 | 240 | |
| | | $I_C = -50 \text{ mA}; V_{CE} = -5 \text{ V}; \text{ see Fig.2}$ | 50 | _ | |
| V _{CEsat} | collector-emitter saturation voltage | $I_C = -10 \text{ mA}; I_B = -1 \text{ mA}$ | _ | -200 | mV |
| | | $I_C = -50 \text{ mA}; I_B = -5 \text{ mA}$ | _ | -500 | mV |
| C _c | collector capacitance | $I_E = i_e = 0; V_{CB} = -10 \text{ V}; f = 1 \text{ MHz}$ | _ | 6 | pF |
| f _T | transition frequency | $I_C = -10 \text{ mA}; V_{CE} = -10 \text{ V}; f = 100 \text{ MHz}$ | 100 | 300 | MHz |
| F | noise figure | $I_C = -200 \mu A; V_{CE} = -5 V; R_S = 2 k\Omega;$ f = 10 Hz to 15.7 kHz | _ | 8 | pF |

PNP high-voltage transistor

2N5401



Philips Semiconductors Product specification

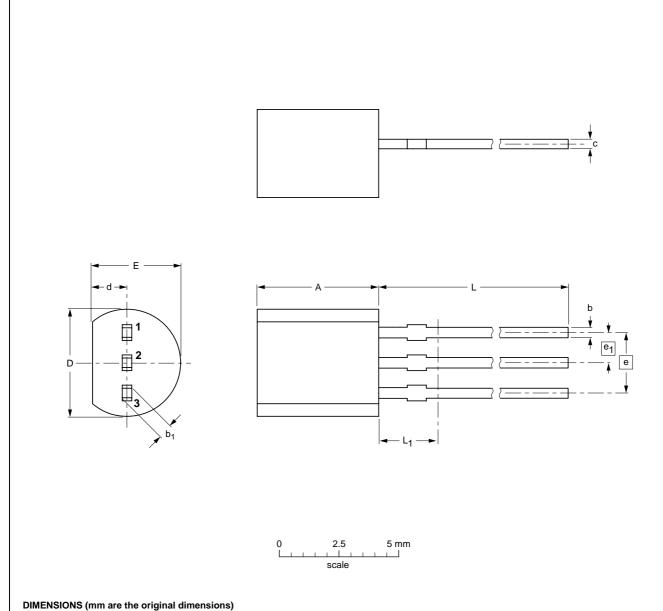
PNP high-voltage transistor

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PACKAGE OUTLINE

Plastic single-ended leaded (through hole) package; 3 leads

SOT54



| UNIT | A | b | b ₁ | С | D | d | E | е | e ₁ | L | L ₁ ⁽¹⁾ |
|------|------------|--------------|----------------|--------------|------------|------------|------------|------|----------------|--------------|-------------------------------|
| mm | 5.2 5.0 | 0.48 0.40 | 0.66 0.56 | 0.45 0.40 | 4.8 4.4 | 1.7 1.4 | 4.2 3.6 | 2.54 | 1.27 | 14.5 12.7 | 2.5 |

1. Terminal dimensions within this zone are uncontrolled to allow for flow of plastic and terminal irregularities.

| OUTLINE | | REFER | ENCES | | EUROPEAN ISSUE DATE | | | | |
|---------|-----|-------|-------|--|---------------------|------------|--|--|--|
| VERSION | IEC | JEDEC | EIAJ | | PROJECTION | ISSUE DATE | | | |
| SOT54 | | TO-92 | SC-43 | | | 97-02-28 | | | |

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DEFINITIONS

| Data sheet status | | |
|---|---|--|
| Objective specification | This data sheet contains target or goal specifications for product development. | |
| Preliminary specification | This data sheet contains preliminary data; supplementary data may be published later. | |
| Product specification | This data sheet contains final product specifications. | |
| Limiting values | | |
| Limiting values given are in accordance with the Absolute Maximum Dating Cystem (ICC 124). Street should be a | | |

Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information

Where application information is given, it is advisory and does not form part of the specification.

LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.

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PNP high-voltage transistor

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